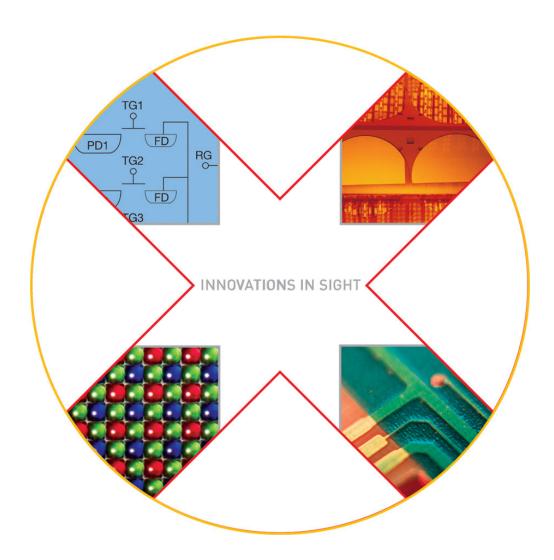




PRELIMINARY DEVICE PERFORMANCE SPECIFICATION

Revision 0.2

March 13, 2006



KODAK KAF-16803 IMAGE SENSOR

4096 (H) X 4096 (V) FULL-FRAME CCD IMAGE SENSOR



TABLE OF CONTENTS

Summary Specification	
Description	
Features	
Applications	
Ordering Information	5
Available Part Configurations	5
Device Description	<i>6</i>
Architecture	
Dark Reference Pixels	
Dummy Pixels	
Internal Test	
Active Buffer Pixels	
Image Acquisition	
Charge Transport	
Horizontal Register	8
Output Structure	8
Output Load	(
Physical Description	10
Pin Description and Device Orientation	10
Pin Description Table	11
Performance	12
Performance	12
Image Performance Specifications	12
Performance Curves	12
Angle Response	
Angle Response Spectral Response Dark Signal	1/
Dark Signal	15
Noise Floor	15
Noise Floor	1/
Cosmetic Operational Conditions	1/
Cosmetic Operational Conditions	1
Absolute Maximum Ratings	15
Power-up Sequence	15
DC Bias Operating Conditions	18
AC Operating Conditions	
Clock Levels	
	19
Timing Requirements Timing Characteristics	
Frame Timing	20
Frame Timing Detail	20
Line Timing	
Pixel Timing Detail	
Timing Edge Alignment	
Example waveforms	
Storage and Handling	
Storage Conditions	
ESD	26 26
COVEL CLASS CALE AND CLEANUNESS	16



Soldering Recommendations	 	26
Mechanical Drawings	 	27
Package		
Quality Assurance And Reliability	 	29
Quality Strategy	 	29
Replacement		
Liability of the Supplier		
Liability of the Customer		
ESD Precautions		
Reliability		
Test Data Retention		
Mechanical		
Warning Life Support Applications Policy		
Revision Changes		30
TABLE OF FIGURES		
Figure 1 - Block Diagram	 	<i>6</i>
Figure 2 - Output Architecture (Left or Right)	 	8
Figure 3 - Recommended Output Structure Load Diagram.	 	9
Figure 4 - Frame Timing	 	20
Figure 5 - Frame Timing Detail	 	20
Figure 6 - Line Timing		21
Figure 4 - Frame Timing	 	21
Figure 8 - Pixel Timing Detail	 	22
Figure 9 - Timing Edge Alignment	 	23
Figure 10 – Completed Assembly Drawing	 	27
3-1-1-1-1-1-1-1-1-1-1-1-1-1-1-1-1-1-1-1	 	· · · · · · · · · · · · · · · · · · ·



SUMMARY SPECIFICATION

KODAK KAF-16803 IMAGE SENSOR

4096 (H) X 4096 (V) FULL FRAME CCD IMAGE SENSOR

DESCRIPTION

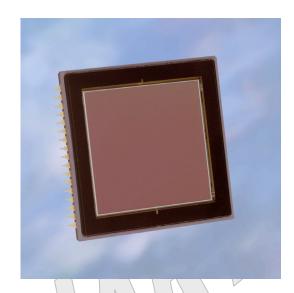
The KAF-16803 image sensor is a redesigned version of the popular KAF-16801E image sensor (4096 x 4096 pixel resolution) with enhancements that specifically target the needs of high performance digital radiography applications. Improvements include enhanced quantum efficiency for improved DQE at higher spatial frequencies, lower noise for improved contrast in areas of high density, and anti-blooming protection to prevent image bleed from over exposure in regions outside the patient. Utilizing Kodak's proprietary single gate ITO process and micro-lens technology, the KAF-16803 image sensor with its large imaging area and small pixel size provides the sensitivity, resolution and contrast necessary for high quality digital radiographs. To simplify device integration, the KAF-16803 image sensor uses the same pin-out and package as the KAF-16801E image sensor.

FEATURES

- High Resolution
- Large Image Area
- High Quantum Efficiency
- Low Noise Architecture
- Broad Dynamic Range

APPLICATIONS

- Digital radiography
- Astronomy
- Life Sciences



Parameter	Typical Value
A m bit at las	Full Frame CCD; with Square
Architecture	Pixels
Total Number of Pixels	4145 (H) x 4128 (V) = 17.1 Mp
Number of Effective Pixels	4127 (H) x 4128 (V) = 17 Mp
Number of Active Pixels	4096(H) x 4096 (V) = 16.8 Mp
Pixel Size	9 μm (H) x 9 μm (V)
Chip Size	38.6 mm (H) x 37.76mm (V)
Aspect Ratio	square
Saturation Signal	85 K e ⁻
Charge to Voltage Conversion	22 μV/e ⁻
Quantum Efficiency (550nm))	55%
Danasaisita (EEO ana)	1302 ke/µJ/cm2
Responsivity (550 nm)	28.7 V/µJ/cm2
Read Noise (f=4 MHz)	9 e ⁻
Dark Signal (T=25°C)	10 e/pix/sec
Dark Current Doubling Temperature	6.6° C
Linear Dynamic Range (f=4 MHz,	76 dB
T=25 C)	76 QB
Blooming Protection	> 100V caturation expecure
(4ms exposure time)	> 100X saturation exposure
Maximum Data Rate	10 MHz



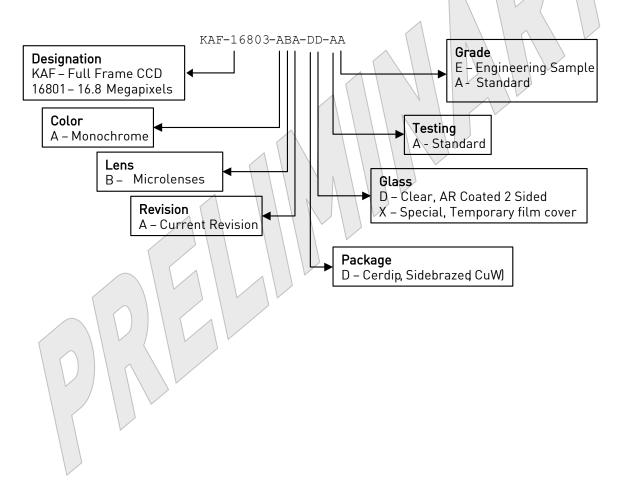
ORDERING INFORMATION

AVAILABLE PART CONFIGURATIONS

The Marking Code on the back of each part is the same for all ordering options, consisting of the text 'KAF-16803-ABA' followed by the serial number of the part.

Available Part Numbers	Description
KAF-16803-ABA-DD-AA	Monochrome, Microlens, CERDIP Package (sidebrazed, CuW), AR coated 2 sides, Standard grade
KAF-16803-ABA-DD-AE	Monochrome, Microlens, CERDIP Package (sidebrazed, CuW), AR coated 2 sides, Engineering sample
KAF-16803-ABA-DX-AA	Monochrome, Microlens, CERDIP Package (sidebrazed, CuW), Temporary film cover, Standard grade
KAF-16803-ABA-DX-AE	Monochrome, Microlens, CERDIP Package (sidebrazed, CuW), Temporary film cover, Engineering sample

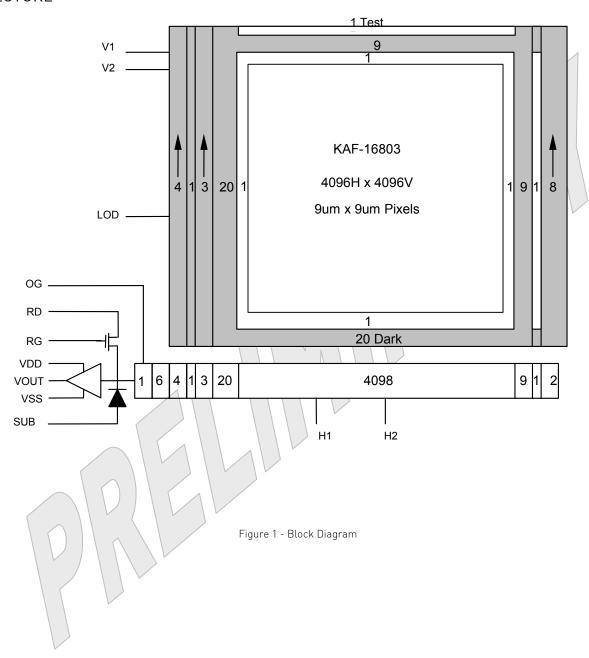
Please contact Image Sensor Solutions for available part numbers.





DEVICE DESCRIPTION

ARCHITECTURE





DARK REFERENCE PIXELS

Surrounding the periphery of the device is a border of light shielded pixels creating a dark region. Within this dark region, exist light shielded pixels that include 20 leading dark pixels on every line. There are also 20 full dark lines at the start and 9 full dark lines at the end of every frame. Under normal circumstances, these pixels do not respond to light and may be used as a *dark reference*.

DUMMY PIXELS

Within each horizontal shift register there are 11 leading pixels. These are designated as *dummy pixels* and should not be used to determine a dark reference level.

INTERNAL TEST

There are some pixels within each line that may not represent dark signal or the signal in the dummy pixels. These are introduced into the design to facilitate production testing. These behave differently than the buffer and dark pixels and should not be used to establish a dark reference.

ACTIVE BUFFER PIXELS

There is 1 photoactive buffer row and column adjacent to the valid photoactive pixels. These may have signals levels different from those in the imaging array and are not counted in the active pixel count.

IMAGE ACQUISITION

An electronic representation of an image is formed when incident photons falling on the sensor plane create electron-hole pairs within the device. These photon-induced electrons are collected locally by the formation of potential wells at each pixel site. The number of electrons collected is linearly dependent on light level and exposure time and non-linearly dependent on wavelength. When the pixel's capacity is reached, excess electrons are discharged into the lateral overflow drain to prevent crosstalk or 'blooming'. During the integration period, the V1 and V2 register clocks are held at a constant (low) level.

CHARGE TRANSPORT

The integrated charge from each pixel is transported to the output using a two-step process. Each line (row) of charge is first transported from the vertical CCDs to a horizontal CCD register using the V1 and V2 register clocks. The horizontal CCD is presented a new line on the falling edge of V2 while H1 is held high. The horizontal CCDs then transport each line, pixel by pixel, to the output structure by alternately clocking the H1 and H2 pins in a complementary fashion.



HORIZONTAL REGISTER

Output Structure

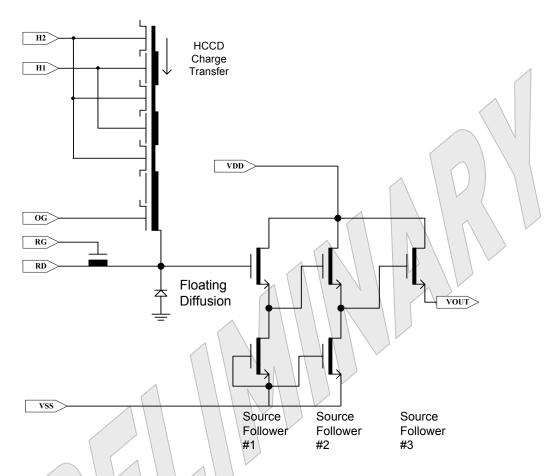


Figure 2 - Output Architecture

The output consists of a floating diffusion capacitance connected to a three-stage source follower. Charge presented to the floating diffusion (FD) is converted into a voltage and is current amplified in order to drive off-chip loads. The resulting voltage change seen at the output is linearly related to the amount of charge placed on the FD. Once the signal has been sampled by the system

electronics, the reset gate (RG) is clocked to remove the signal and FD is reset to the potential applied by reset drain (RD). Increased signal at the floating diffusion reduces the voltage seen at the output pin. To activate the output structure, an off-chip current source must be added to the VOUT pin of the device. See Figure 3.



Output Load

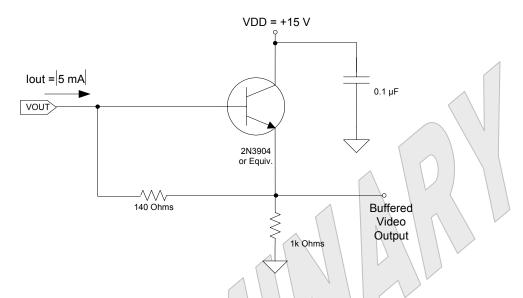


Figure 3 - Recommended Output Structure Load Diagram.

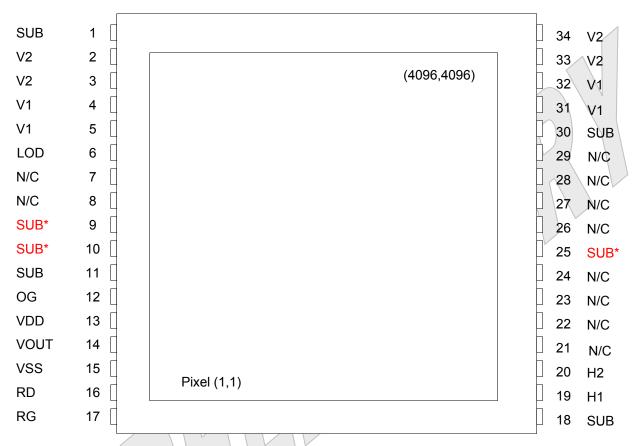
Note: Component values may be revised based on operating conditions and other design considerations.





PHYSICAL DESCRIPTION

PIN DESCRIPTION AND DEVICE ORIENTATION



Note: Pins with the same name are to be tied together on the circuit board and have the same timing.

Notes:

* Unlike the KAF-16801E, pins 9, 10, and, 25 are internally connected to SUB. They may be connected to SUB on the printed circuit board or must be left floating



PIN DESCRIPTION TABLE

Die	Marra	Description
Pin 1	Name SUB	Description Cub streets
2		Substrate Vertical CCD Clock-Phase 2
3	V2 V2	
4	V2 V1	Vertical CCD Clock-Phase 2
		Vertical CCD Clock-Phase 1
5	V1	Vertical CCD Clock-Phase 1
6	LOD	Anti Blooming Drain
7	N/C	No Connection
8	N/C	No Connection
9	SUB*	Substrate or No Connection
10	SUB*	Substrate or No Connection
11	SUB	Substrate
12	OG	Output Gate
13	VDD	Output Amplifier Supply
14	VOUT	Video Output:
15	VSS	Output Amplifier Return
16	RD	Reset Drain
17	RG	Reset Gate
18	SUB	Substrate
19	H1	Horizontal Phase 1
20	H2	Horizontal Phase 2
21	N/C	No Connection
22	N/C	No Connection
23	N/C	No Connection
24	N/C	No Connection
25	SUB*	Substrate or No Connection
26	N/C	No Connection
27	N/C	No Connection
28	N/C	No Connection
29	N/C	No Connection
30	SUB	Substrate
31	V1	Vertical CCD Clock-Phase 1
32	V1	Vertical CCD Clock-Phase 1
33	V2	Vertical CCD Clock-Phase 2
34	V2	Vertical CCD Clock-Phase 2

Notes:

Unlike the KAF-16801E, pins 9, 10, and, 25 are internally connected to SUB. They may be connected to SUB on the printed circuit board or must be left floating



PERFORMANCE

IMAGE PERFORMANCE OPERATIONAL CONDITIONS

Description	Condition - Unless otherwise noted	Notes
Frame time (t _{readout} + t _{int})		Includes overclock pixels
Integration time (tint)	variable	
Horizontal clock frequency	4 MHz	
Temperature	> 20°C	Room temperature
Mode	integrate – readout cycle	
Operation	Nominal operating voltages and timing with min. vertical pulse width t_{Vw} = 20 μ s	

IMAGE PERFORMANCE SPECIFICATIONS

The parameters in green and violet reflect measured values. The green values have changed from the design predictions, the violet values have not changed and are as predicted. Other values are predicted (not yet measured) values.

Description	Symbol	Min.	Nom.	Max.	Units	Notes	Sample Plan
Saturation Signal	Ne ⁻ sat	1	85k		e-		die
Quantum Efficiency 550 nm	Rg		60		%QE	1	design
Photoresponse Non-Linearity	PRNL		M		%	2	
Photoresponse Non-Uniformity	PRNU				%	3	
Integration Dark Signal	Vdark,int		10 2		e/pix/sec pA/cm²	4	die
Dark Signal Non-Uniformity	DSNU			50	e/pix/sec	5	die
Dark Signal Doubling Temperature	ΔΤ		6.3		°C		design
Read Noise	NR		10		e ⁻ rms	6	die
Linear Dynamic Range	DR		84		dB	7	design
Blooming Protection	X_ab	100			x Esat	8	design
Output Amplifier Sensitivity	Vout/Ne⁻		22		μV/e		
DC Offset, output amplifier	Vodc		Vrd – 3.0		V	9	die
Output Amplifier Bandwidth	f _{-3dB}		100		MHz		design
Output Impedance, Amplifier	ROUT		160		Ohms		die

www.kodak.com/go/imagers



Notes:

- 1. Increasing output load currents to improve bandwidth will decrease these values.
- 2. Worst case deviation from straight line fit, between 1% and 90% of Vsatmin.
- 3. One Sigma deviation of a 128x128 sample when CCD illuminated uniformly.
- 4. Average of all pixels with no illumination at 25 °C.
- 5. Average dark signal of any of 32 x 32 blocks within the sensor. (each block is 128 x 128 pixels)
- 6. Output amplifier noise at 25 °C ,operating at pixel frequency up to 4MHz, bandwidth <20MHz, tint = 0, and no dark current shot noise.
- 7. $20\log(V_{sat}/V_{N})$
- 8. X_ab is the number of times above the Vsat illumination level that the sensor will bloom by spot size doubling. The spot size is 10% of the imager height. X_ab is measured at 4ms.
- 9. Video level offset with respect to ground.

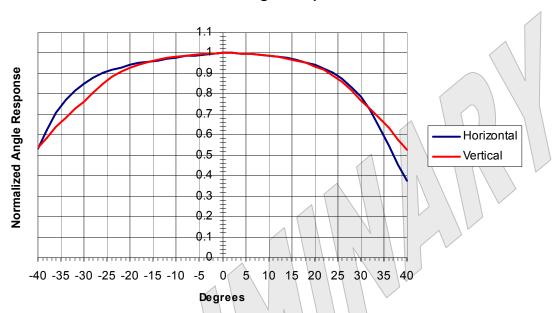




PERFORMANCE CURVES

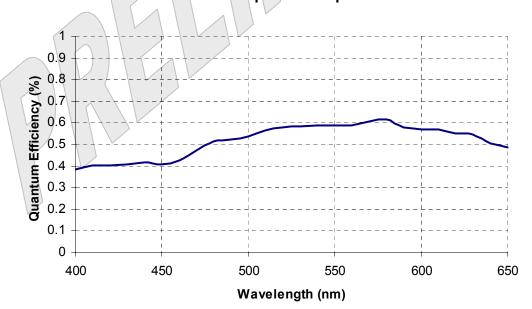
Angle Response

KAF-16803 Angle Response



Spectral Response

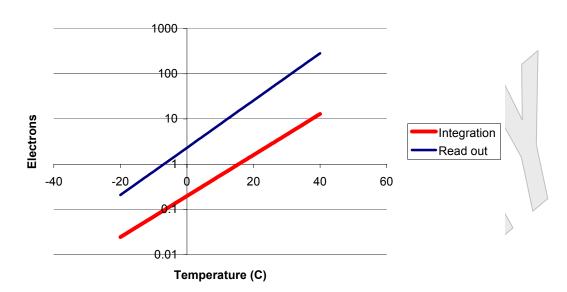
KAF-16803 Spectral Response





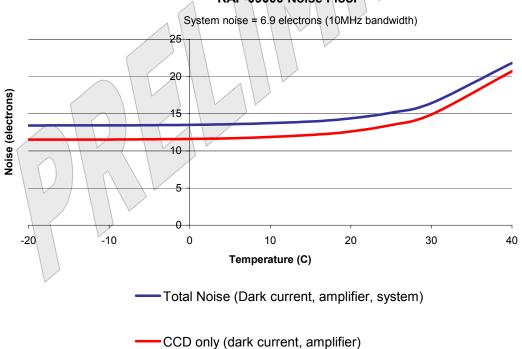
Dark Signal

KAF-16803 Dark Current



Noise Floor

KAF-09000 Noise Floor





COSMETIC SPECIFICATIONS

Cosmetic Operational Conditions

All cosmetic tests performed at T~25 °C

Points	Clusters	Columns
<200	<20	<10

Definitions

Point Defects

Dark: A pixel which deviates by more than 6% from neighboring pixels when illuminated to 70% of saturation

-- OR --

Bright: A Pixel with dark current >3,000 e/pixel/sec at 25C

Cluster Defect

A grouping of not more than 10 adjacent point defects

Cluster defects are separated by no less than 4 good pixels in any direction

Column Defect

A grouping of more than 10 point defects along a single column

-- OR --

A column containing a pixel with dark current > 15,000e/pixel/sec (bright column)

-- OR --

A column that does not meet the CTE specification for all exposures less than the specified Max sat. signal level and greater than 2 Ke

--\OR --

A column that contains a pixel which loses more than 250 e under 2Ke illumination (trap defect)

Column defects are separated by no less than 4 good columns. No multiple column defects (double or more) will be permitted.

Column and cluster defects are separated by at least 4 good columns in the x direction.



OPERATION

ABSOLUTE MAXIMUM RATINGS

Description ⁹	Symbol	Minimum	Maximum	Units	Notes
Diode Pin Voltages	V _{diode}	-0.5	+20	V	1,2
Gate Pin Voltages	V _{gate1}	-16	+16	V	1,3
Adjacent Gate Voltages	V ₁₋₂	-16	+16	V	4
Output Bias Current	l _{out}		-30	mA	5
LODT Diode Voltage	V_{LODT}	-0.5	+13.0	V	1
Operating Temperature	Tnp	-60	60	°C\	7

Notes:

- 1. Referenced to pin VSUB
- 2. Includes pins: VRD, VDD, VSS, VOUT.
- 3. Includes pins: V1, V2, H1, H2, RG, V0G.
- 4. Voltage difference between adjacent gates. Includes: V1 to V2; H1 to H2; H1 to V0G; and V1 to H2.
- 5. Avoid shorting output pins to ground or any low impedance source during operation. Amplifier bandwidth increases at higher currents and lower load capacitance at the expense of reduced gain (sensitivity).
- 6. Absolute maximum rating is defined as a level or condition that should not be exceeded at any time per the description. If the level or condition is exceeded, the device will be degraded and may be damaged.
- 7. Noise performance will degrade at higher temperatures.

POWER-UP SEQUENCE

The sequence chosen to perform an initial power-up is not critical for device reliability. A coordinated sequence may minimize noise and the following sequence is recommended:

- 1. Connect the ground pins (VSUB).
- 2. Supply the appropriate biases and clocks to the remaining pins.



DC BIAS OPERATING CONDITIONS

Description	Symbol	Minimum	Nominal	Maximum	Units	Maximum DC Current (mA)	Notes
Reset Drain	V_{RD}		13		V	$I_{RD} = 0.01$	
Output Amplifier Return	VV_{SS}		2.0		V	$I_{SS} = 3.0$	
Output Amplifier Supply	VV_{DD}		15.0*		V	I _{out} + I _{ss}	
Substrate	V _{SUB}		0		V	0.01	
Output Gate	V _{OG}		6.0**		V	0.01	
Lateral Overflow Drain	V _{LOD}		8.0		V	0.01	
Video Output Current	I _{out}		-5		mΑ		\ \ 1

^{*} Vdd may be specified as high as 17.0 before this part is released to production.

Notes:

1. An output load sink must be applied to VOUT to activate output amplifier - see Figure 3.

AC OPERATING CONDITIONS

Clock Levels

Description	Symbol	Level	Minimum	Nominal	Maximum	Units	Effective Capacitance	Notes
V1 Low Level	V1L	Low		-9.0		V	250 nF	1
V1 High Level	V1H	High		2.5		V		1
V2 Low Level	V2L	Low		-9.0		V	250 nF	1
V2 High Level	V2H	High		2.5		V		1
H1 Low Level	H1L	Low		-3.0		V	500 pF	1
H1 High Level	H1H	High	1	7.0		V		1
H2 Low Level	H2L	Low		-3.0		V	300 pF	1
H2 High Level	Н2Н	High		7.0		V		1
RG Low Level	V _{RGL}	Low		6.0		V	13 pF	1
RG High Level	V _{RGH}	High		11.0		V		1
						•		•

Notes:

1. All pins draw less than 10 µA DC current. Capacitance values relative to SUB (substrate).

^{**} The output gate bias will be changed before this part is released to production. The new value will be approximately 2.0 volts.



Timing Requirements

Description	Symbol	Minimum	Nominal	Maximum	Units	Notes
H1, H2 Clock Frequency	f _H		4	10	MHz	1
H1, H2 Rise, Fall Times	t _{H1r} ,t _{H1f}	5			%	3
V1, V2 Rise, Fall Times	t _{V1r} ,t _{V1f}	5			%	3
V1 - V2 Cross-over	V _{VCR}	-1	0	1	V	
H1 - H2 Cross-over	V _{HCR}			0	V	1
H1, H2 Setup Time	t _{HS}	5	10		μs	
RG Clock Pulse Width	t _{RGw}	5			ns	4
V1, V2 Clock Pulse Width	t _{Vw}	20	20		μs	

Timing Characteristics

Description	Symbol	Minimum	Nominal	Maximum	Units	Notes
Pixel Period (1 Count)	t _e		250		ns	2
Integration Time	t _{int}		-			5
Line Time	t _{line}		1.08		ms	6
Readout Time	t _{readout}		4,450		ms	7

Notes:

- 1. 50% duty cycle values.
- 2. CTE will degrade above the maximum frequency.
- 3. Relative to the pulse width (based on 50% of high/low levels).
- 4. RG should be clocked continuously.
- 5. Integration time is user specified.
- 6. $[4145 * t_e] + t_{HS} + [2 * t_{VW}] = 1.08 \text{ msec}$
- 7. $t_{readout} = t_{line} * 4128 lines$.



8.

Frame Timing

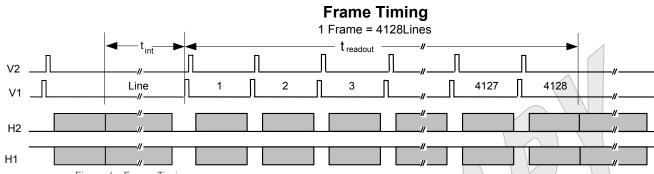
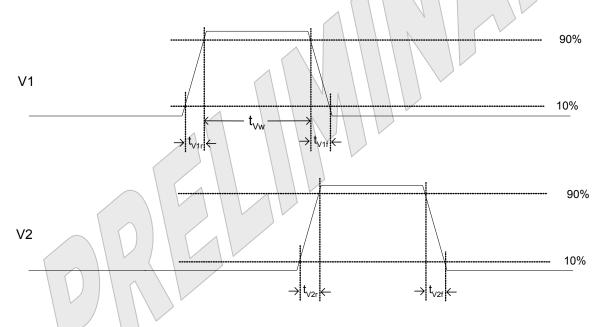


Figure 4 - Frame Timing

Frame Timing Detail



www.kodak.com/go/imagers

Figure 5 - Frame Timing Detail



Line Timing

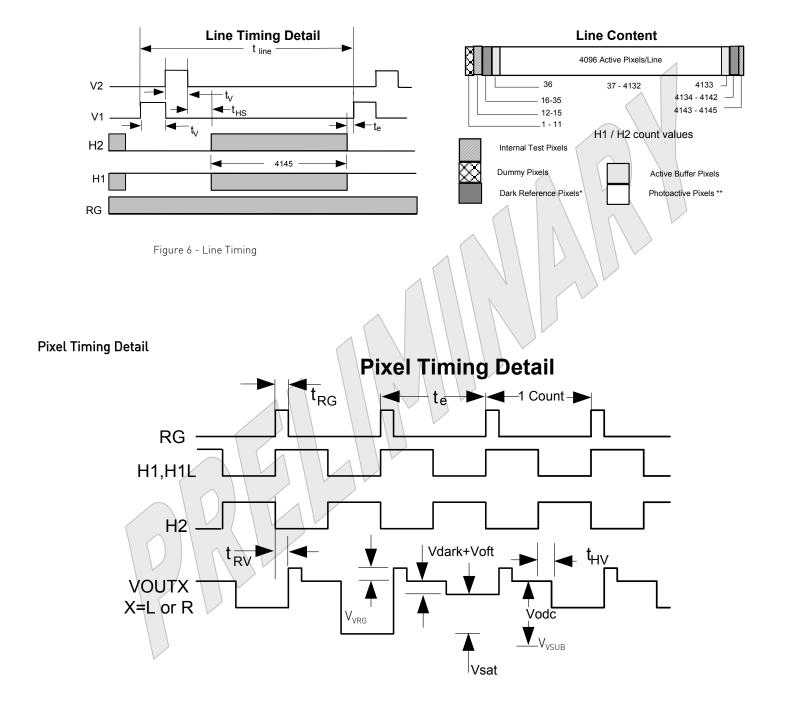
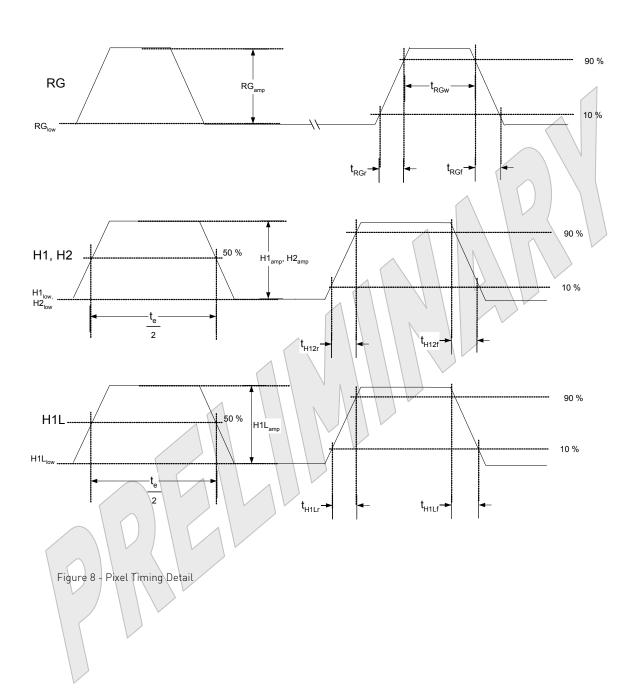


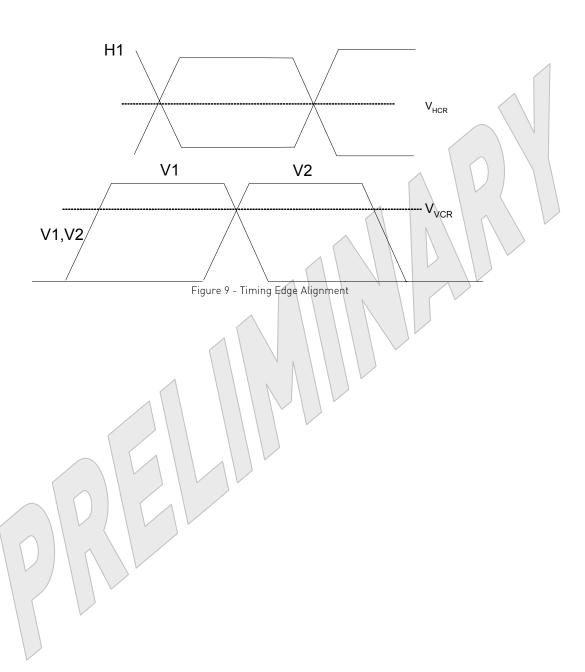
Figure 7 - Pixel Timing







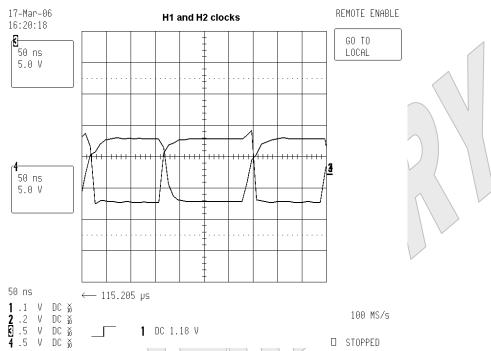
Timing Edge Alignment



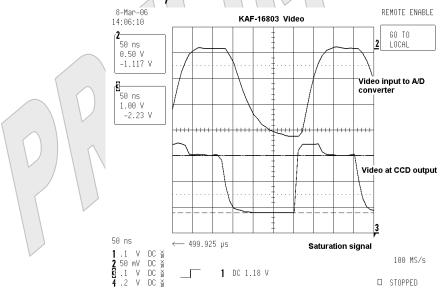


EXAMPLE WAVEFORMS

Horizontal CCD clocks

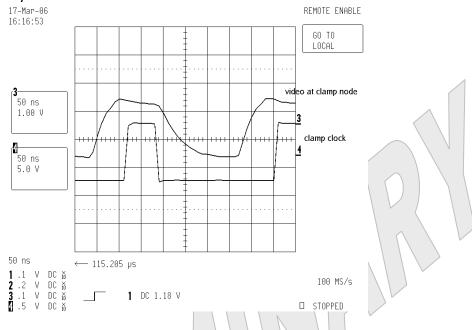


Video Waveform – at the CCD output and bandwidth limited at the analog to digital converter.

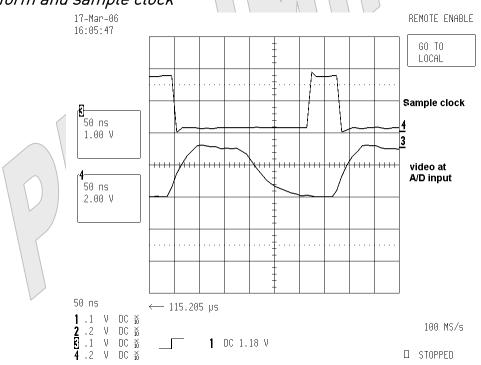




Video waveform and clamp clock



Video waveform and sample clock





STORAGE AND HANDLING

STORAGE CONDITIONS

Description	Symbol	Minimum	Maximum	Units	Notes
Storage Temperature	T _{ST}	-20	70	°C	1

Note:

 Long-term storage toward the maximum temperature will accelerate color filter degradation

FSD

This device contains limited protection against Electrostatic Discharge (ESD) and is rated as a Class 0 device, JESD22 Human Body, and Class A, JESD22 Machine Mode

Devices should be handled in accordance with strict handling precautions. See ISS Application Note MTD/PS-0224, "Electrostatic Discharge Control".

COVER GLASS CARE AND CLEANLINESS

- 1. The cover glass is highly susceptible to particles and other contamination. Perform all assembly operations in a clean environment.
- 2. Touching the cover glass must be avoided.

Caution: Improper cleaning of the cover glass may damage these devices. Refer to Application Note MTD/PS-0237, "Cover Glass Cleaning Procedure for Image Sensors"

SOLDERING RECOMMENDATIONS

Partial Heating Method: 280 °C maximum pin temperature; 10 seconds maximum duration per pin.



MECHANICAL DRAWINGS

PACKAGE

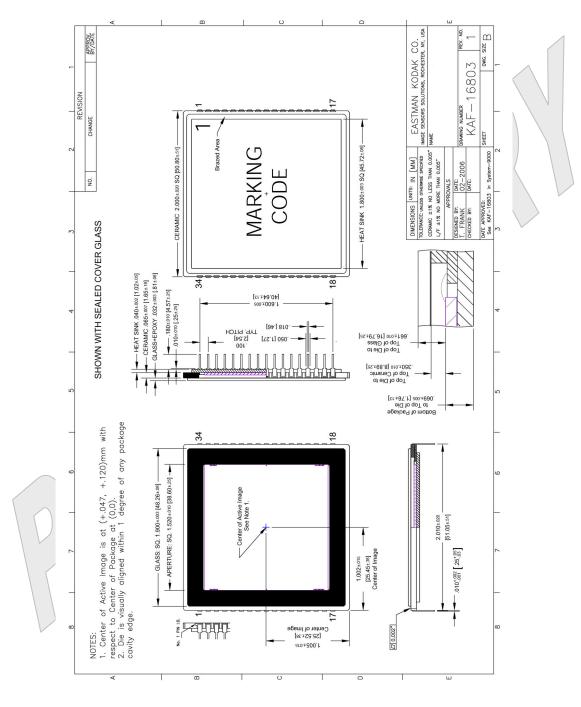
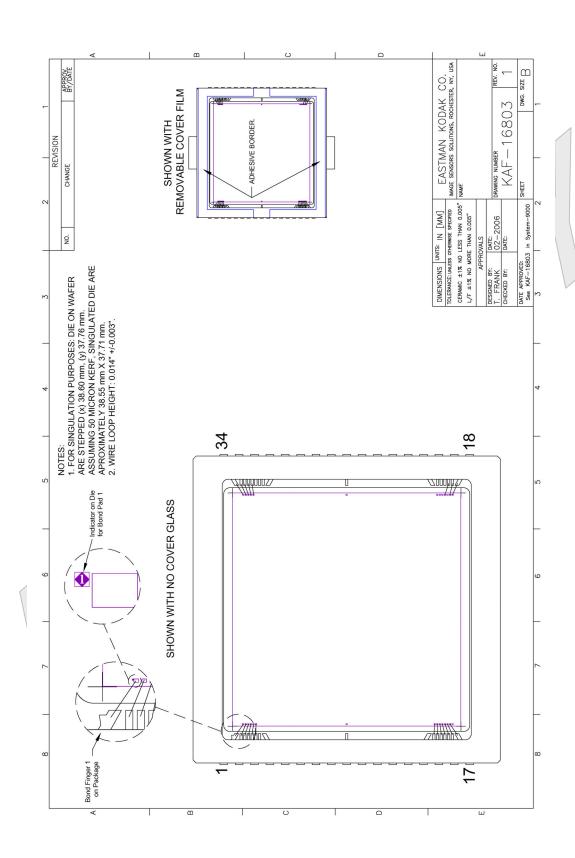


Figure 10 - Completed Assembly Drawing







QUALITY ASSURANCE AND RELIABILITY

Quality Strategy

All image sensors will conform to the specifications stated in this document. This will be accomplished through a combination of statistical process control and inspection at key points of the production process. Typical specification limits are not guaranteed but provided as a design target. For further information refer to ISS Application Note MTD/PS-0292, Quality and Reliability.

Replacement

All devices are warranted against failure in accordance with the terms of Terms of Sale. This does not include failure due to mechanical and electrical causes defined as the liability of the customer below.

Liability of the Supplier

A reject is defined as an image sensor that does not meet all of the specifications in this document upon receipt by the customer.

Liability of the Customer

Damage from mechanical (scratches or breakage), electrostatic discharge (ESD) damage, or other electrical misuse of the device beyond the stated absolute maximum ratings, which occurred after receipt of the sensor by the customer, shall be the responsibility of the customer.

ESD Precautions

Devices are shipped in static-safe containers and should only be handled at static-safe workstations. See ISS Application Note MTD/PS-0224 for handling recommendations.

Reliability

Information concerning the quality assurance and reliability testing procedures and results are available from the Image Sensor Solutions and can be supplied upon request. For further information refer to ISS Application Note MTD/PS-0292, Quality and Reliability.

Test Data Retention

Image sensors shall have an identifying number traceable to a test data file. Test data shall be kept for a period of 2 years after date of delivery.

Mechanical

The device assembly drawing is provided as a reference. The device will conform to the published package tolerances.



Address all inquiries and purchase orders to:

Image Sensor Solutions Eastman Kodak Company Rochester, New York 14650-2010

Phone: (585) 722-4385 Fax: (585) 477-4947

E-mail: imagers@kodak.com

Kodak reserves the right to change any information contained herein without notice. All information furnished by Kodak is believed to be accurate.

WARNING LIFE SUPPORT APPLICATIONS POLICY

Kodak image sensors are not authorized for and should not be used within Life Support Systems without the specific written consent of the Eastman Kodak Company. Product warranty is limited to replacement of defective components and does not cover injury or property or other consequential damages.

REVISION CHANGES

Revision Number	Description of Changes
0.1	First Preliminary version
0.2	Corrected Available Part Configurations formatting and glass designator Added measured data Revised operating voltages Revised bright defect definition (slightly tighter thresholds) Replaced package drawing





Page intentionally left blank.





Page intentionally left blank.

